

and -5.0

View Online at https://aerobasegroup.com/nsn/5961-01-108-8766

Inclosure Material:	
Ceramic	
Overall Length:	
Between 0.660 inches and 0.785 inches	
Overall Height:	
0.200 inches	
Overall Width:	
0.325 inches	
Component Name And Quantity:	
4 transistor	
Mounting Method:	
Press fit	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
-60.0 collector to base voltage/static/emitter o	open all transistor and -40.0 collector to emitter voltage/static/base open all transistor
emitter to base voltage, static, collector open	all transistor
Current Rating Per Characteristic:	
-600.00 milliamperes source cutoff current all	transistor
Maximum Operating Tempurature Per Meas	surement Point:
200.0 degrees celsius junction	
Special Features:	
All transistor junction pattern arrangement: pn	ιp
Terminal Type And Quantity:	
14 pin	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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